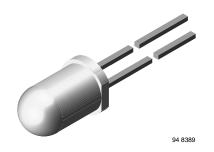


Vishay Semiconductors

High Speed Infrared Emitting Diode, 850 nm, GaAIAs Double Hetero



DESCRIPTION

TSHG6210 is an infrared, 850 nm emitting diode in GaAlAs double hetero (DH) technology with high radiant power and high speed, molded in a clear, untinted plastic package.

FEATURES

- Package type: leaded
- Package form: T-1³/₄
- Dimensions (in mm): \varnothing 5
- Peak wavelength: $\lambda_p = 850 \text{ nm}$
- High reliability
- High radiant power
- High radiant intensity
- Angle of half intensity: $\phi = \pm 10^{\circ}$
- Low forward voltage
- Suitable for high pulse current operation
- High modulation bandwidth: $f_c = 18 \text{ MHz}$
- · Good spectral matching with CMOS cameras
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

APPLICATIONS

- Infrared radiation source for operation with CMOS cameras
- High speed IR data transmission
- Smoke-automatic fire detectors

PRODUCT SUMMARY

COMPONENT	l _e (mW/sr)	φ (deg)	λ _p (nm)	t _r (ns)	
TSHG6210	230	± 10	850	20	

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMAT	ΓΙΟΝ		
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
TSHG6210	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾

Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V _R	5	V	
Forward current		I _F	100	mA	
Peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I _{FM}	200	mA	
Surge forward current	t _p = 100 μs	I _{FSM}	1	А	
Power dissipation		Pv	180	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T _{amb}	- 40 to + 85	°C	
Storage temperature range		T _{stg}	- 40 to + 100	°C	
Soldering temperature	$t \leq$ 5 s, 2 mm from case	T _{sd}	260	°C	
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R _{thJA}	230	K/W	

Note

Tamb = 25 °C, unless otherwise specified



TSHG6210

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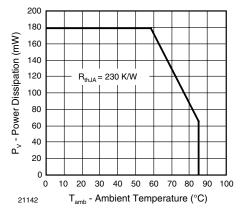


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

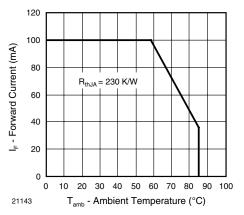


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 100 mA, t _p = 20 ms	V _F		1.5	1.8	V
	I _F = 1 A, t _p = 100 μs	V _F		2.3		V
Temperature coefficient of V _F	I _F = 1 mA	TK _{VF}		- 1.8		mV/K
Reverse current	V _R = 5 V	I _R			10	μA
Junction capacitance	$V_{R} = 0 V, f = 1 MHz, E = 0$	Cj		125		pF
De die at interación	I _F = 100 mA, t _p = 20 ms	le	140	230	420	mW/sr
Radiant intensity	I _F = 1 A, t _p = 100 μs	l _e		2300		mW/sr
Radiant power	l _F = 100 mA, t _p = 20 ms	φ _e		55		mW
Temperature coefficient of ϕ_{e}	I _F = 100 mA	TKφe		- 0.35		%/K
Angle of half intensity		φ		± 10		deg
Peak wavelength	I _F = 100 mA	λρ	820	850	880	nm
Spectral bandwidth	I _F = 100 mA	Δλ		40		nm
Temperature coefficient of λ_p	I _F = 100 mA	ΤΚλρ		0.25		nm/K
Rise time	I _F = 100 mA	t _r		20		ns
Fall time	I _F = 100 mA	t _f		13		ns
Cut-off frequency	$I_{DC} = 70 \text{ mA}, I_{AC} = 30 \text{ mA pp}$	f _c		18		MHz
Virtual source diameter		d		3.7		mm

Note

 $T_{amb} = 25$ °C, unless otherwise specified



High Speed Infrared Emitting Diode, Vishay Semiconductors 850 nm, GaAlAs Double Hetero

TSHG6210

BASIC CHARACTERISTICS

 T_{amb} = 25 °C, unless otherwise specified

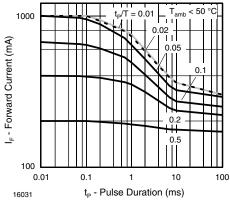


Fig. 3 - Pulse Forward Current vs. Pulse Duration

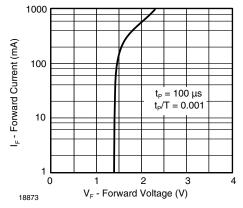


Fig. 4 - Forward Current vs. Forward Voltage

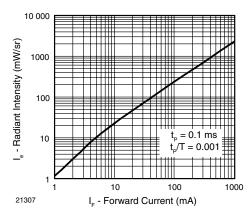
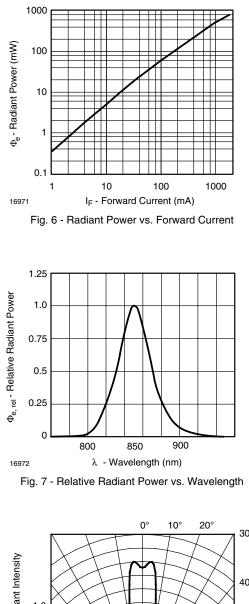


Fig. 5 - Radiant Intensity vs. Forward Current



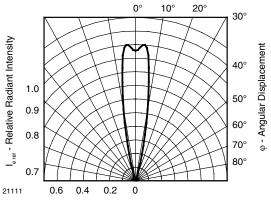
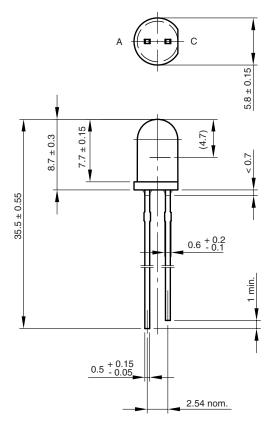


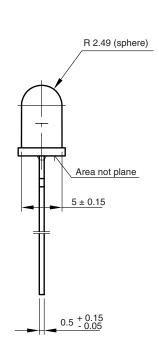
Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

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PACKAGE DIMENSIONS in millimeters







technical drawings according to DIN specifications

6.544-5259.02-4 Issue: 8; 19.05.09 95 10917



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